

JAERI-Tech
99-059



JP9950533



GAIN MEASUREMENTS OF Ti : SAPPHIRE AMPLIFIER

September 1999

Koji TAMURA and Takashi ARISAWA

日本原子力研究所
Japan Atomic Energy Research Institute

本レポートは、日本原子力研究所が不定期に公刊している研究報告書です。

入手の間合わせは、日本原子力研究所研究情報部研究情報課（〒319-1195 茨城県那珂郡東海村）あて、お申し越しください。なお、このほかに財団法人原子力弘済会資料センター（〒319-1195 茨城県那珂郡東海村日本原子力研究所内）で複写による実費頒布をおこなっております。

This report is issued irregularly.

Inquiries about availability of the reports should be addressed to Research Information Division, Department of Intellectual Resources, Japan Atomic Energy Research Institute, Tokai-mura, Naka-gun, Ibaraki-ken 〒319-1195, Japan.

©Japan Atomic Energy Research Institute, 1999

編集兼発行 日本原子力研究所

Gain Measurements of Ti:sapphire Amplifier

Koji TAMURA and Takashi ARISAWA⁺

Department of Materials Science
Tokai Research Establishment
Japan Atomic Energy Research Institute
Tokai-mura, Naka-gun, Ibaraki-ken

(Received July 13, 1999)

Ti:sapphire laser pulses from an oscillator were amplified by the pumping of a second harmonics of Nd:YAG laser, and output laser power was measured. By extrapolating the laser power ratio with and without pump laser to extracted power of zero, single-pass and double-pass small-signal gains as a function of incident pump energy density were obtained. The single-pass small signal gain was calculated by means of two level rate equation, which reproduced experimental results well. Based on these results, the oscillator output was amplified in a series of amplifier chain.

Keywords: Ti:sapphire Laser, Amplifier, Small-signal Gain, Nd:YAG Laser, Single Pass, Double Pass

⁺ Advanced Photon Research Center, Kansai Research Establishment

チタンサファイア増幅部の利得測定

日本原子力研究所東海研究所物質科学研究部

田村 浩司・有沢 孝*

(1999 年 7 月 13 日受理)

チタンサファイア共振器からのレーザーパルスをヤグレーザーの第二高調波により励起することにより増幅し、出力レーザーパワーを測定した。ポンプレーザーによる励起がある場合とない場合のレーザー出力強度比を、取り出しエネルギーゼロの領域まで外挿することにより、シングルパスとダブルパスの小信号利得を、励起レーザー光密度の関数として測定した。シングルパスの利得を 2 準位のレート方程式により計算した。得られた計算結果は実験結果をよく再現した。この結果に基づき、共振器出力を多段階増幅部を用いて増幅した。

東海研究所：〒319-1195 茨城県那珂郡東海村白方白根 2-4

* 関西研究所光量子科学研究センター

Contents

1. Introduction	1
2. Experimental Method	1
3. Results and Discussion	2
4. Conclusion	4
Acknowledgement	4
References	4

目 次

1. はじめに	1
2. 実験方法	1
3. 結果と考察	2
4. まとめ	4
謝辞	4
参考文献	4

This is a blank page.

1. Introduction

Several advantageous features of Ti:sapphire laser (TSL) such as broad gain region, easy handling of solid state brick, and stable operation without vibration by dye circulation, make TSL potentially useful light source for high resolution spectroscopy and laser isotope separation¹⁾. As a light source for laser isotope separation, broad tunability, narrow linewidth with a single-longitudinal mode and stable operation are desirable, which are attainable with a TSL oscillator. For the isotope separation on a large scale or frequency conversion of the fundamental output with a nonlinear crystal to obtain shorter wavelengths, high laser pulse energy is required. The laser pulse can be amplified by a master-oscillator power-amplifier (MOPA) chain in series.²⁾

In this study, single-pass and double-pass small-signal gains of a Ti:sapphire crystal pumped by the second harmonics of Nd:YAG laser were measured. Based on the results, the TSL oscillator pulse was amplified in a series of amplifier.

2. Experimental method

Figure 1 shows the schematics of the experimental setup for single-pass (a) and double-pass (b) gain measurements. The Ti:sapphire crystal (18mm length) was obtained from Union Carbide Co. The titanium concentration was 0.15% by weight. The absorption coefficients for π -polarization at 532 nm and 800 nm were 1.9 cm^{-1} and 0.05 cm^{-1} , respectively. It was mounted at Brewster's angle on a holder at room temperature.

The crystal was longitudinally pumped by the second harmonics of Q-switched Nd:YAG laser (Lumonics HY1200) operated at 10 Hz. The pump laser was focused with a lens and injected from an end of the crystal. The temporal duration of the pump laser was 10nsec. The polarization of the pump laser was parallel to the c-axis of the crystal (π -polarization).

As a signal laser, TSL oscillator was used. The oscillator consisted of a Ti:sapphire crystal, a grating (1800 line/mm), a tuning mirror, and a total reflector. By grazing-incidence configuration and cavity length control, single-longitudinal mode operation with linewidth less than 500 MHz was possible. The intensity of the signal laser was attenuated with ND filters. The signal laser was introduced almost collinearly with the pump laser into the crystal 25 nsec after the pump laser pulse. Figure 2 shows the temporal profile of the pump laser and the probe laser at the entrance of the crystal. For single-pass gain measurement shown in figure 1(a), the introduced signal laser was amplified by the pumped crystal, and the laser output was detected with a power meter. The signal was detected as an average of ten pump pulses. For double-pass configuration shown in figure 1(b), the amplified laser was reflected with a back mirror, and amplified in the crystal again. The overlap of the pump laser and the signal laser was optimized to give highest output power.

3. Results and discussion

Figure 3 shows the output laser power measured with (I) and without (I_0) YAG laser pumping at the laser wavelength of 808 nm. Figure 4 shows the relation between the observed signal gain (I/I_0) and the incident pump energy density at the introduced probe laser power between 110 μJ (a) and 770 μJ (c). The results show that the gain increased with the pump energy density, and it decreased with the signal laser power. Figure 5 shows the relations between the gain (I/I_0) and the extracted power ($I-I_0$) obtained at the pump energy density of 4.3 J/cm². By extrapolating the relation to the extracted power of zero, small-signal gain g_0 averaged over the crystal length L at each pump energy was determined. Figure 6 summarizes the obtained small-signal gain for single-pass (a) and double-pass (b) as a function of incident pump energy density. The results show that small-signal gain increased linearly with the pump energy density and the gain for double-pass was about twice that of single-pass.

Figure 7 shows the wavelength dependence of double-pass small signal gain at the pump energy density of 4.3 J/cm². The results show that the gain was largest at about 780 nm.

The single-pass gain of the laser pulse was calculated based on a two level rate equation formulation.

$$\frac{\partial N_1(x,t)}{\partial t} = \sigma_{ap} I_p(x) N_0(x,t) - N_1(x,t) \sigma_e I_l(x,t) + N_0(x,t) \sigma_a I_l(x,t) - N_1(x,t) / \tau \quad (1)$$

$$\frac{\partial I_l(x,t)}{\partial x} = N_1(x,t) \sigma_e I_l(x,t) - N_0(x,t) \sigma_a I_l(x,t) \quad (2)$$

where $N_1(x,t)$ and $N_0(x,t)$ are the concentration of titanium ions in excited level and ground level, respectively, $I_p(x)$ and $I_l(x,t)$ are the internal photon intensities of pump laser and signal laser, σ_{ap} is the absorption cross-section of pump laser, σ_e is the cross-section for stimulated emission from excited level to ground level, σ_a is the absorption cross-section of signal laser from ground level to excited level, and τ is the radiative decay time of the excited level. Considering that the pump laser was introduced before the signal laser and that the fluorescence time is long enough compared with the travel time of laser pulse in the crystal, equation (2) is approximated by,

$$\frac{dI_l(x)}{dx} = [(\sigma_e + \sigma_a) \sigma_{ap} I_p(x) \exp(-\alpha_p(L-x)) \exp(-\Delta t / \tau) - \sigma_a] N I_l(x) \quad (3)$$

where L is the length of the crystal, N is the concentration of Ti³⁺ ions ($=N_1+N_0$), α_p is the absorption coefficient of the pump laser, and Δt is delay time of signal laser to pump laser.

Figure 8 shows the horizontal spatial profile of pump laser (a) and probe laser (b).

From the experimental observation, the spatial profile of the pump laser was assumed to be a circular beam. Before injection to the crystal, the pump laser was focused, and the increase of pump laser cross-section in the crystal during the propagation was considered. The number of photon of the pump laser at the distance of x from the crystal end was given by,

$$I_p = \frac{E_p}{h\nu_p} \frac{1}{S(x)}$$

where E_p is the introduced pump energy, $h\nu_p$ is the photon energy of the pump laser, and $S(x)$ is the cross section of the pump laser at a distance of x from the end of the crystal. The spatial profile of the signal laser was assumed to be Gaussian as shown in figure 8(b). The number of photon of the signal laser $I(r)$ was given by,

$$I(r) = I_0 \exp[-2(r/r_0)^2]$$

$$I_0 = \frac{2P_t}{\pi r_0^2 h\nu_l}$$

where P_t is the energy of signal laser, r is the distance from the center of the laser beam, r_0 is the radius of the signal laser, and $h\nu_l$ is the photon energy of the signal laser. Equations (1) and (3) were solved numerically, and from the laser intensity ratio at the entrance and the exit of the crystal, signal gain was obtained. In this calculation, the radiative decay time of the excited level τ ($=3.15 \times 10^{-6}$ sec)³⁾, the cross-section for stimulated emission σ_e ($=2.7 \times 10^{-19}$ cm²)³⁾, the absorption cross-section of pump laser σ_{ap} ($=9.3 \times 10^{-20}$ cm²)⁴⁾ were obtained from references. The delay time of the signal laser from the pump laser Δt was 25 nsec, and the crystal length L was 18 mm. The concentration of titanium ions N ($=2.0 \times 10^{19}$ /cm³), the absorption cross-section of pump laser σ_{ap} ($=9.3 \times 10^{-20}$ sec²), and the absorption cross-section of signal laser σ_s ($=2.2 \times 10^{-21}$ cm²) were determined from the absorption coefficient of the crystal.⁵⁾ The solid line in figure 6 denoted by Cal shows the calculated results of the small signal gain. The experimental results for single-pass were well reproduced by the calculations.

The oscillator output was amplified in a series of amplifiers. The oscillator output of 0.62 mJ by the pump input of 66 mJ was amplified at the initial stage amplifier (AMP 1, double pass), and output energy of 63 mJ by the pump power of 137 mJ was obtained. Considering the damage of the back mirror, single pass amplifier was used in the following stages. The output from AMP 1 was amplified by AMP 2 (single pass), and output of 88 mJ was obtained by the pump input of 43 mJ. It was then amplified by AMP 3 (single pass) where output of 154 mJ was obtained by the pump input of 68 mJ, and by AMP 4 (single pass) where output of 186 mJ was obtained by the pump input of 140 mJ. The gain at each stage was also shown in figure 6 by AMP1~AMP 4.

4. Conclusion

Ti:sapphire laser pulses from an oscillator were amplified by the pumping of a second harmonics of Nd:YAG laser, and single-pass and double-pass small-signal gains as a function of incident pump energy density were obtained. The single-pass small signal gain was calculated by two level rate equation, which reproduced the experimental results well. Based on these results, the oscillator output was amplified in a series of amplifier chain.

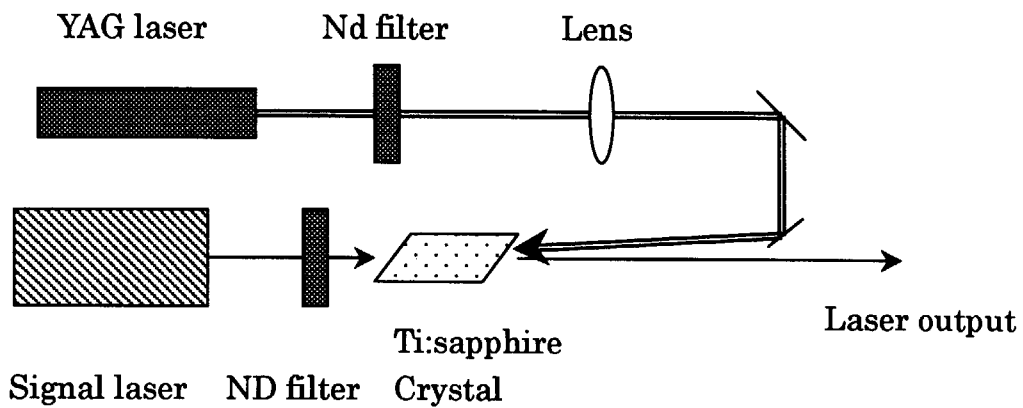
Acknowledgement

The authors are grateful to Mr. T. Shimizu for his assistance in this study.

References

- 1) Greenland P. T.: Contemp. Phys., 31, 405 (1990).
- 2) Barnes J. C., Barnes N. P. and Miller G. E.: IEEE J. Quantum Electron., 24, 1029 (1988).
- 3) Moulton P. F.: J. Opt. Soc. Am., B3, 125 (1986).
- 4) Sanchez A., Strauss A. J., Aggarwal R. L. and Fahey R. E.: IEEE J. Quantum Electron., 24, 995 (1988).
- 5) Wall K. F., Aggarwal R. L., Fahey R. E. and Strauss A. J.: IEEE J. Quantum Electron., 24, 1016 (1988).

(a) Single pass



(b) Double pass

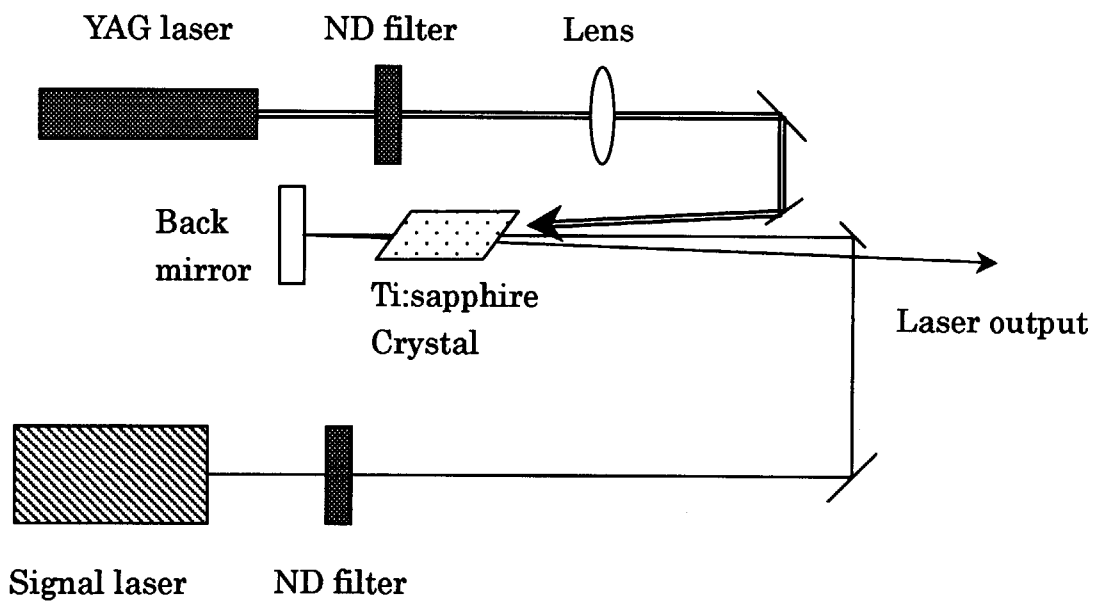


Fig. 1 Schematics of the experimental setup for the measurements of single-pass (a) and double-pass (b) small-signal gain in a Ti:sapphire amplifier.

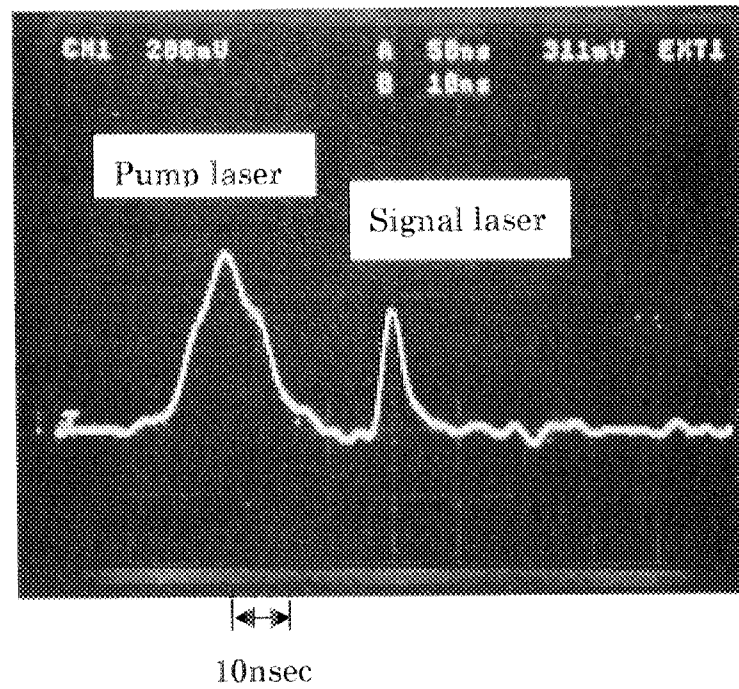


Fig. 2 Temporal pulse shape of pump laser and signal laser at the entrance of crystal.

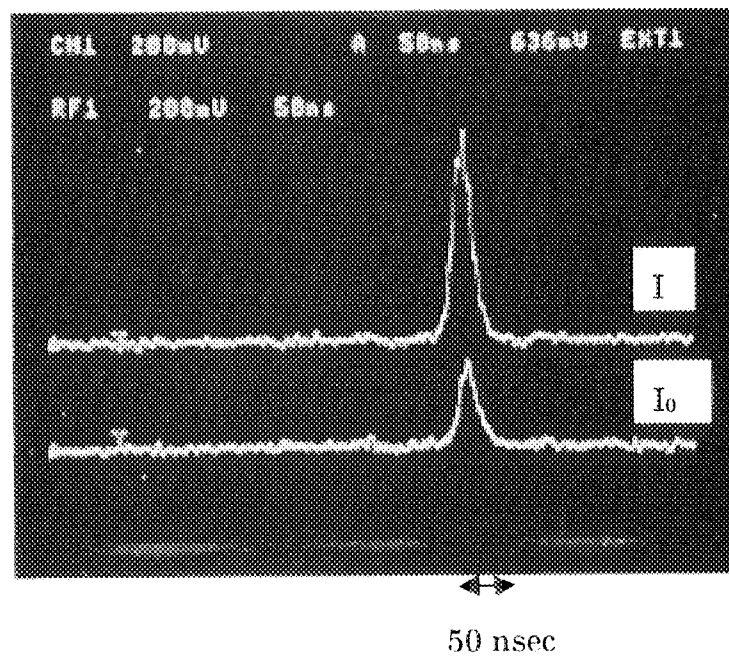


Fig. 3 Temporal pulse shape of output laser from Ti:sapphire amplifier crystal with (I) and without (I_0) YAG laser pumping.

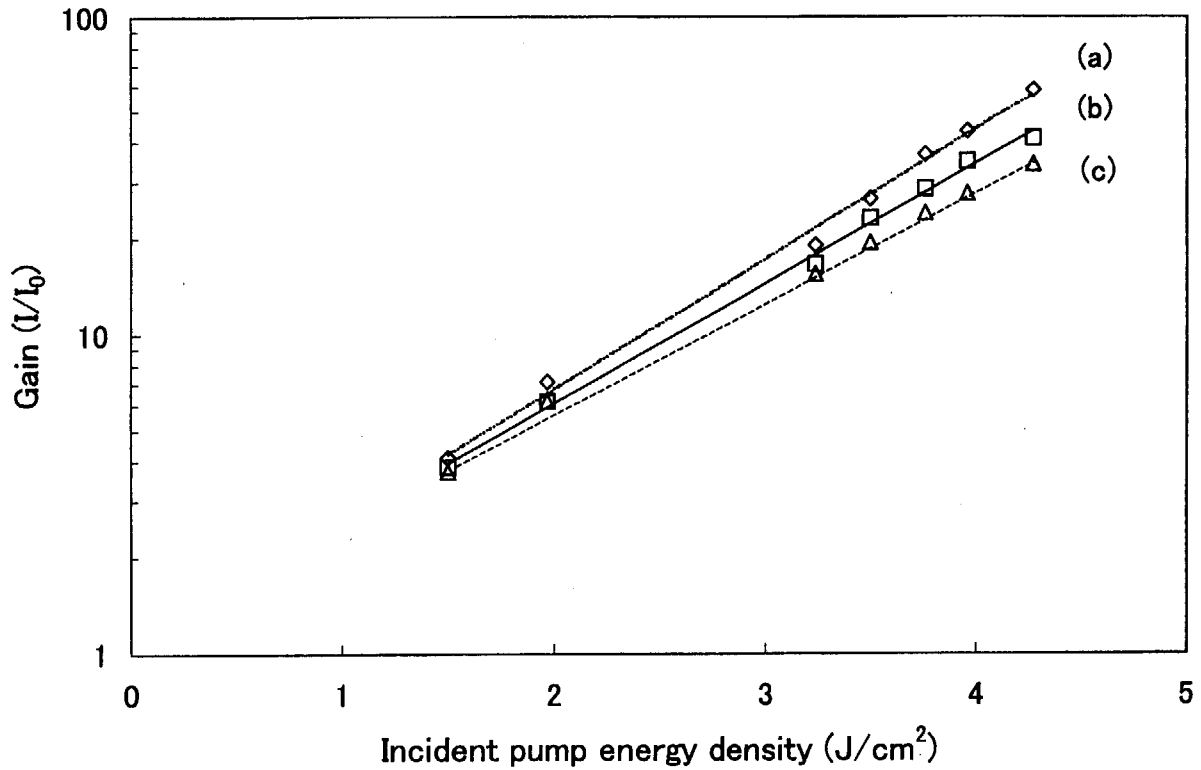


Fig. 4 The obtained gain (the ratio of the output laser intensity with (I) and without (I_0) pump laser) as a function of pump laser density. The incident signal laser power was $110 \mu\text{J}$ (a), $420 \mu\text{J}$ (b) and $770 \mu\text{J}$ (c).

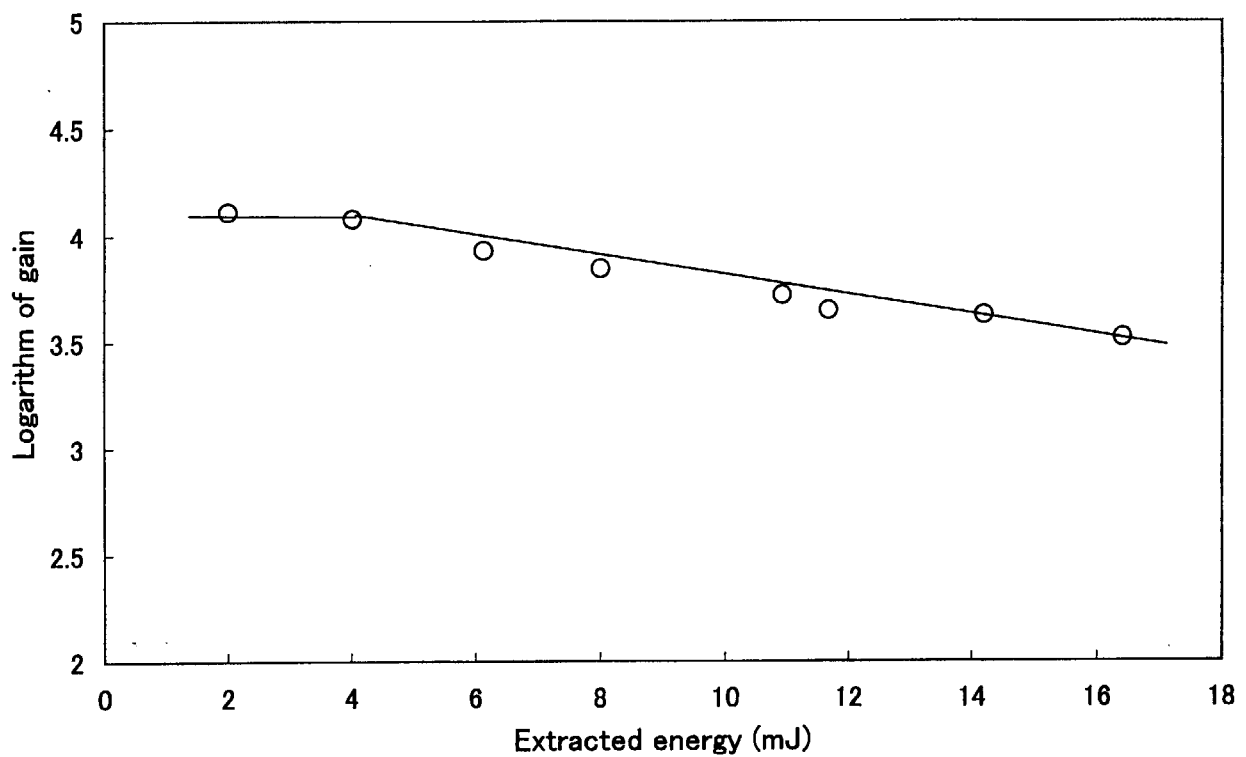


Fig. 5 The relation of logarithm of gain (I/I_0) and extracted power ($I-I_0$) at the pump energy density of 4.3 J/cm^2 .

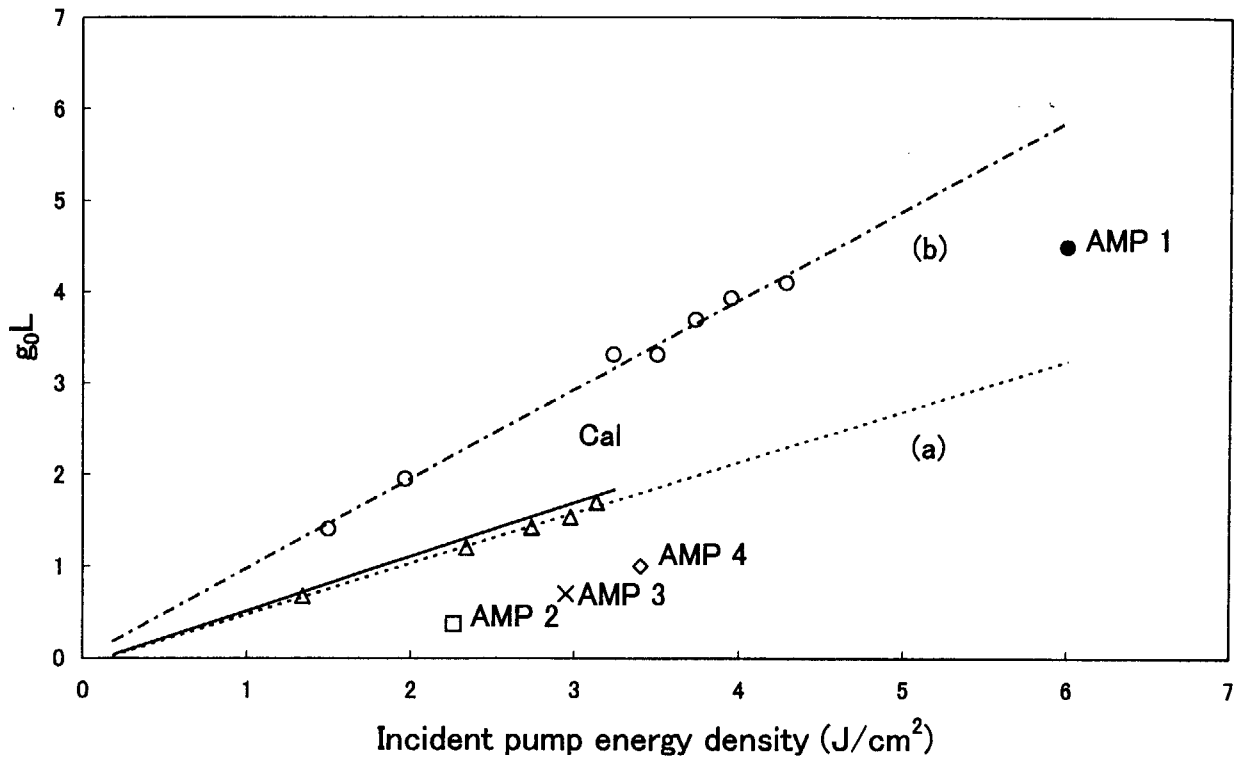


Fig. 6 The exponential gain g_0L for single-pass (a) and double-pass (b) as a function of pump energy density. The results of calculation are also shown by solid line denoted by Cal. The gain for each stage of amplifier is denoted by AMP 1 – AMP 4.

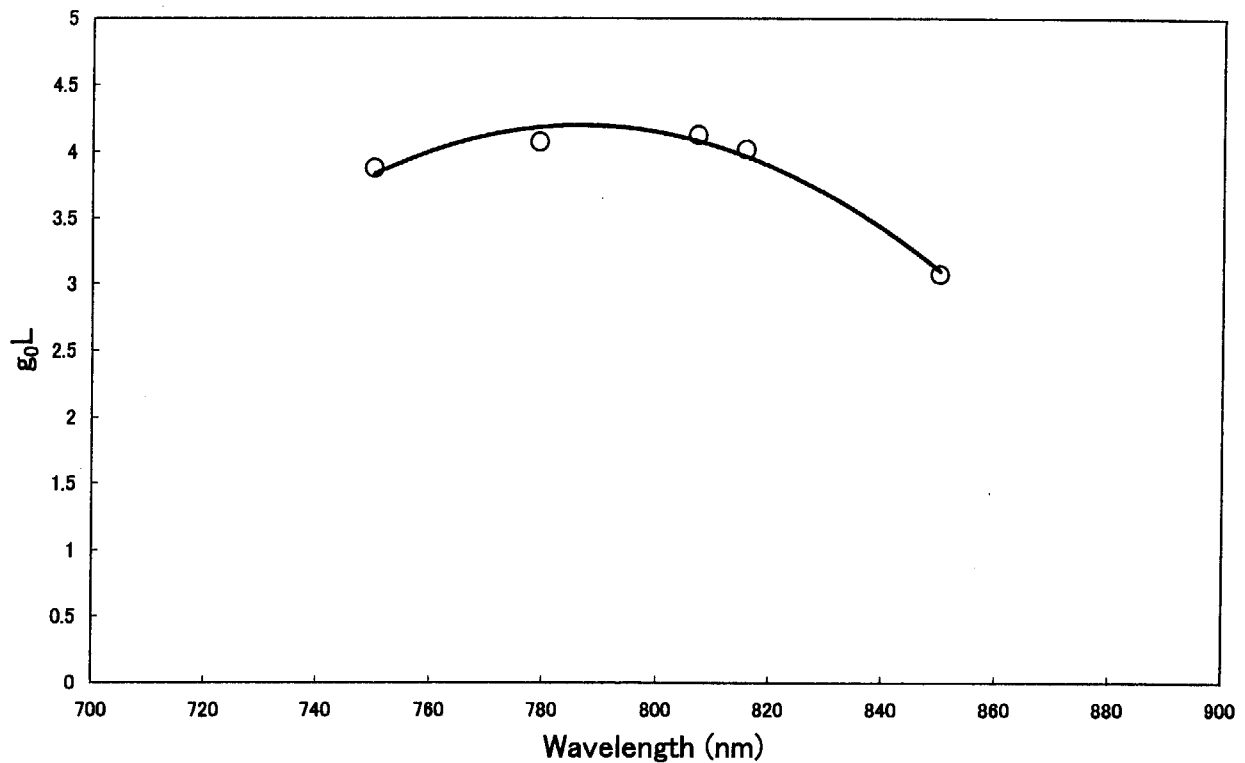
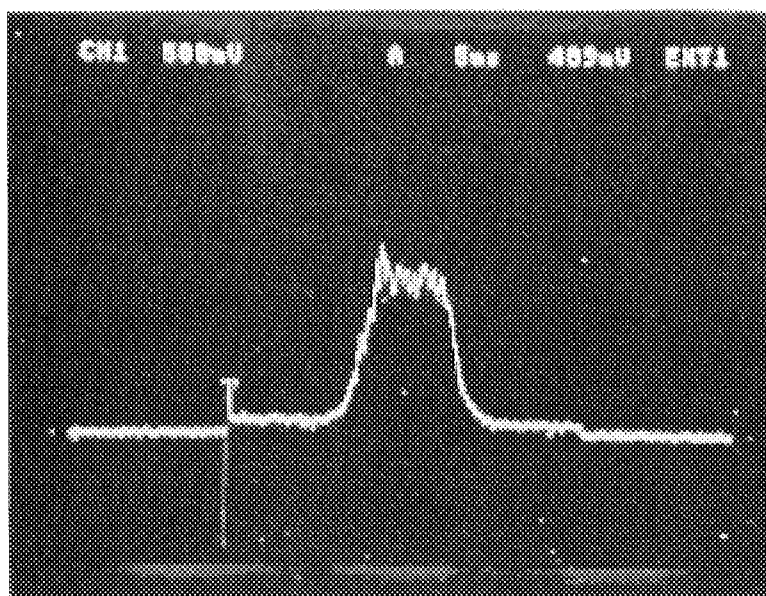


Fig. 7 Experimental double-pass small-signal gain as a function of wavelength of the output laser at the pump energy density of 4.3 J/cm^2 .

(a) Pump laser



(b) Signal laser

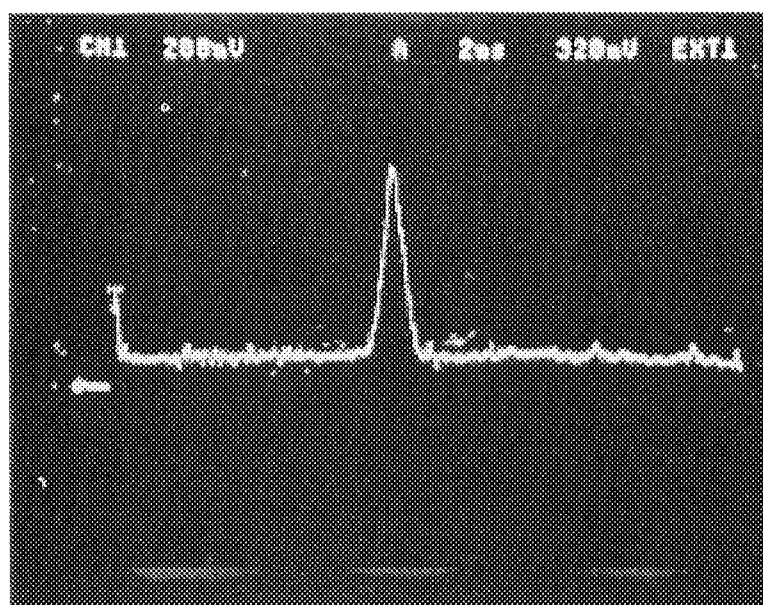


Fig. 8 Horizontal spatial profiles of pump laser (a) and signal laser (b).

This is a blank page.

国際単位系 (SI) と換算表

表1 SI基本単位および補助単位

量	名称	記号
長さ	メートル	m
質量	キログラム	kg
時間	秒	s
電流	アンペア	A
熱力学温度	ケルビン	K
物質質量	モル	mol
光度	カンデラ	cd
平面角	ラジアン	rad
立体角	ステラジアン	sr

表3 固有の名称をもつ SI 組立単位

量	名称	記号	他の SI 単位 による表現
周波数	ヘルツ	Hz	s ⁻¹
力	ニュートン	N	m·kg/s ²
圧力, 応力	パスカル	Pa	N/m ²
エネルギー, 仕事, 熱量	ジュール	J	N·m
工率, 放射束	ワット	W	J/s
電気量, 電荷	クーロン	C	A·s
電位, 電圧, 起電力	ボルト	V	W/A
静電容量	ファラド	F	C/V
電気抵抗	オーム	Ω	V/A
コンダクタンス	ジーメンズ	S	A/V
磁束	ウェーバ	Wb	V·s
磁束密度	テスラ	T	Wb/m ²
インダクタンス	ヘンリー	H	Wb/A
セルシウス温度	セルシウス度	°C	
光束	ルーメン	lm	cd·sr
照度	ルクス	lx	lm/m ²
放射能	ベクレル	Bq	s ⁻¹
吸収線量	グレイ	Gy	J/kg
線量当量	シーベルト	Sv	J/kg

表2 SI と併用される単位

名称	記号
分, 時, 日	min, h, d
度, 分, 秒	°, ', "
リットル	l, L
トン	t
電子ボルト	eV
原子質量単位	u

$$1 \text{ eV} = 1.60218 \times 10^{-19} \text{ J}$$

$$1 \text{ u} = 1.66054 \times 10^{-27} \text{ kg}$$

表4 SI と共に暫定的に維持される単位

名称	記号
オングストローム	Å
バ	b
バ	bar
ガ	Gal
キュリー	Ci
レントゲン	R
ラ	rad
レ	rem

$$1 \text{ Å} = 0.1 \text{ nm} = 10^{-10} \text{ m}$$

$$1 \text{ b} = 100 \text{ fm}^2 = 10^{-28} \text{ m}^2$$

$$1 \text{ bar} = 0.1 \text{ MPa} = 10^5 \text{ Pa}$$

$$1 \text{ Gal} = 1 \text{ cm/s}^2 = 10^{-2} \text{ m/s}^2$$

$$1 \text{ Ci} = 3.7 \times 10^{10} \text{ Bq}$$

$$1 \text{ R} = 2.58 \times 10^{-4} \text{ C/kg}$$

$$1 \text{ rad} = 1 \text{ cGy} = 10^{-2} \text{ Gy}$$

$$1 \text{ rem} = 1 \text{ cSv} = 10^{-2} \text{ Sv}$$

表5 SI 接頭語

倍数	接頭語	記号
10 ¹⁸	エクサ	E
10 ¹⁵	ペタ	P
10 ¹²	テラ	T
10 ⁹	ギガ	G
10 ⁶	メガ	M
10 ³	キロ	k
10 ²	ヘクト	h
10 ¹	デカ	da
10 ⁻¹	デシ	d
10 ⁻²	センチ	c
10 ⁻³	ミリ	m
10 ⁻⁶	マイクロ	μ
10 ⁻⁹	ナノ	n
10 ⁻¹²	ピコ	p
10 ⁻¹⁵	フェムト	f
10 ⁻¹⁸	アト	a

(注)

- 表1～5は「国際単位系」第5版, 国際度量衡局 1985年刊行による。ただし, 1 eV および 1 u の値は CODATA の 1986 年推奨値によった。
- 表4には海里, ノット, アール, ヘクタールも含まれているが日常の単位なのでここでは省略した。
- bar は, JIS では流体の圧力を表わす場合に限り表2のカテゴリーに分類されている。
- EC 閣僚理事会指令では bar, barn および「血圧の単位」mmHg を表2のカテゴリーに入れている。

換算表

力	N (=10 ⁵ dyn)	kgf	lbf
	1	0.101972	0.224809
	9.80665	1	2.20462
	4.44822	0.453592	1

$$\text{粘度 } 1 \text{ Pa} \cdot \text{s} (\text{N} \cdot \text{s} / \text{m}^2) = 10 \text{ P (ポアズ)} (\text{g} / (\text{cm} \cdot \text{s}))$$

$$\text{動粘度 } 1 \text{ m}^2 / \text{s} = 10^4 \text{ St (ストークス)} (\text{cm}^2 / \text{s})$$

圧	MPa (=10 bar)	kgf/cm ²	atm	mmHg (Torr)	lbf/in ² (psi)
	1	10.1972	9.86923	7.50062 × 10 ³	145.038
力	0.0980665	1	0.967841	735.559	14.2233
	0.101325	1.03323	1	760	14.6959
	1.33322 × 10 ⁻⁴	1.35951 × 10 ⁻³	1.31579 × 10 ⁻³	1	1.93368 × 10 ⁻²
	6.89476 × 10 ⁻³	7.03070 × 10 ⁻²	6.80460 × 10 ⁻²	51.7149	1

エネルギー・仕事・熱量	J (=10 ⁷ erg)	kgf·m	kW·h	cal (計量法)	Btu	ft·lbf	eV
	1	0.101972	2.77778 × 10 ⁻⁷	0.238889	9.47813 × 10 ⁻⁴	0.737562	6.24150 × 10 ¹⁸
	9.80665	1	2.72407 × 10 ⁻⁶	2.34270	9.29487 × 10 ⁻³	7.23301	6.12082 × 10 ¹⁹
	3.6 × 10 ⁶	3.67098 × 10 ⁵	1	8.59999 × 10 ⁵	3412.13	2.65522 × 10 ⁶	2.24694 × 10 ²⁵
	4.18605	0.426858	1.16279 × 10 ⁻⁶	1	3.96759 × 10 ⁻³	3.08747	2.61272 × 10 ¹⁹
	1055.06	107.586	2.93072 × 10 ⁻⁴	252.042	1	778.172	6.58515 × 10 ²¹
	1.35582	0.138255	3.76616 × 10 ⁻⁷	0.323890	1.28506 × 10 ⁻³	1	8.46233 × 10 ¹⁸
	1.60218 × 10 ⁻¹⁹	1.63377 × 10 ⁻²⁰	4.45050 × 10 ⁻²⁶	3.82743 × 10 ⁻²⁰	1.51857 × 10 ⁻²²	1.18171 × 10 ⁻¹⁹	1

$$1 \text{ cal} = 4.18605 \text{ J (計量法)}$$

$$= 4.184 \text{ J (熱化学)}$$

$$= 4.1855 \text{ J (15 °C)}$$

$$= 4.1868 \text{ J (国際蒸気表)}$$

$$\text{仕事率 } 1 \text{ PS (仏馬力)}$$

$$= 75 \text{ kgf} \cdot \text{m/s}$$

$$= 735.499 \text{ W}$$

放射能	Bq	Ci
	1	2.70270 × 10 ⁻¹¹
	3.7 × 10 ¹⁰	1

吸収線量	Gy	rad
	1	100
	0.01	1

照射線量	C/kg	R
	1	3876
	2.58 × 10 ⁻⁴	1

線量当量	Sv	rem
	1	100
	0.01	1

GAIN MEASUREMENTS OF TI : SAPPHIRE AMPLIFIER

